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### Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	2560
Number of Logic Elements/Cells	2560
Total RAM Bits	32768
Number of I/O	93
Number of Gates	162000
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	144-BGA
Supplier Device Package	144-FBGA (13x13)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/intel/ep20k60efc144-1">https://www.e-xfl.com/product-detail/intel/ep20k60efc144-1</a>

- Flexible clock management circuitry with up to four phase-locked loops (PLLs)
  - Built-in low-skew clock tree
  - Up to eight global clock signals
  - ClockLock<sup>®</sup> feature reducing clock delay and skew
  - ClockBoost<sup>®</sup> feature providing clock multiplication and division
  - ClockShift<sup>™</sup> programmable clock phase and delay shifting
- Powerful I/O features
  - Compliant with peripheral component interconnect Special Interest Group (PCI SIG) *PCI Local Bus Specification, Revision 2.2* for 3.3-V operation at 33 or 66 MHz and 32 or 64 bits
  - Support for high-speed external memories, including DDR SDRAM and ZBT SRAM (ZBT is a trademark of Integrated Device Technology, Inc.)
  - Bidirectional I/O performance ( $t_{CO} + t_{SU}$ ) up to 250 MHz
  - LVDS performance up to 840 Mbits per channel
  - Direct connection from I/O pins to local interconnect providing fast  $t_{CO}$  and  $t_{SU}$  times for complex logic
  - MultiVolt I/O interface support to interface with 1.8-V, 2.5-V, 3.3-V, and 5.0-V devices (see [Table 3](#))
  - Programmable clamp to  $V_{CCIO}$
  - Individual tri-state output enable control for each pin
  - Programmable output slew-rate control to reduce switching noise
  - Support for advanced I/O standards, including low-voltage differential signaling (LVDS), LVPECL, PCI-X, AGP, CTT, stub-series terminated logic (SSTL-3 and SSTL-2), Gunning transceiver logic plus (GTL+), and high-speed terminated logic (HSTL Class I)
  - Pull-up on I/O pins before and during configuration
- Advanced interconnect structure
  - Four-level hierarchical FastTrack<sup>®</sup> Interconnect structure providing fast, predictable interconnect delays
  - Dedicated carry chain that implements arithmetic functions such as fast adders, counters, and comparators (automatically used by software tools and megafunctions)
  - Dedicated cascade chain that implements high-speed, high-fan-in logic functions (automatically used by software tools and megafunctions)
  - Interleaved local interconnect allows one LE to drive 29 other LEs through the fast local interconnect
- Advanced packaging options
  - Available in a variety of packages with 144 to 1,020 pins (see [Tables 4 through 7](#))
  - FineLine BGA<sup>®</sup> packages maximize board space efficiency
- Advanced software support
  - Software design support and automatic place-and-route provided by the Altera<sup>®</sup> Quartus<sup>®</sup> II development system for

Each LE has two outputs that drive the local, MegaLAB, or FastTrack Interconnect routing structure. Each output can be driven independently by the LUT's or register's output. For example, the LUT can drive one output while the register drives the other output. This feature, called register packing, improves device utilization because the register and the LUT can be used for unrelated functions. The LE can also drive out registered and unregistered versions of the LUT output.

The APEX 20K architecture provides two types of dedicated high-speed data paths that connect adjacent LEs without using local interconnect paths: carry chains and cascade chains. A carry chain supports high-speed arithmetic functions such as counters and adders, while a cascade chain implements wide-input functions such as equality comparators with minimum delay. Carry and cascade chains connect LEs 1 through 10 in an LAB and all LABs in the same MegaLAB structure.

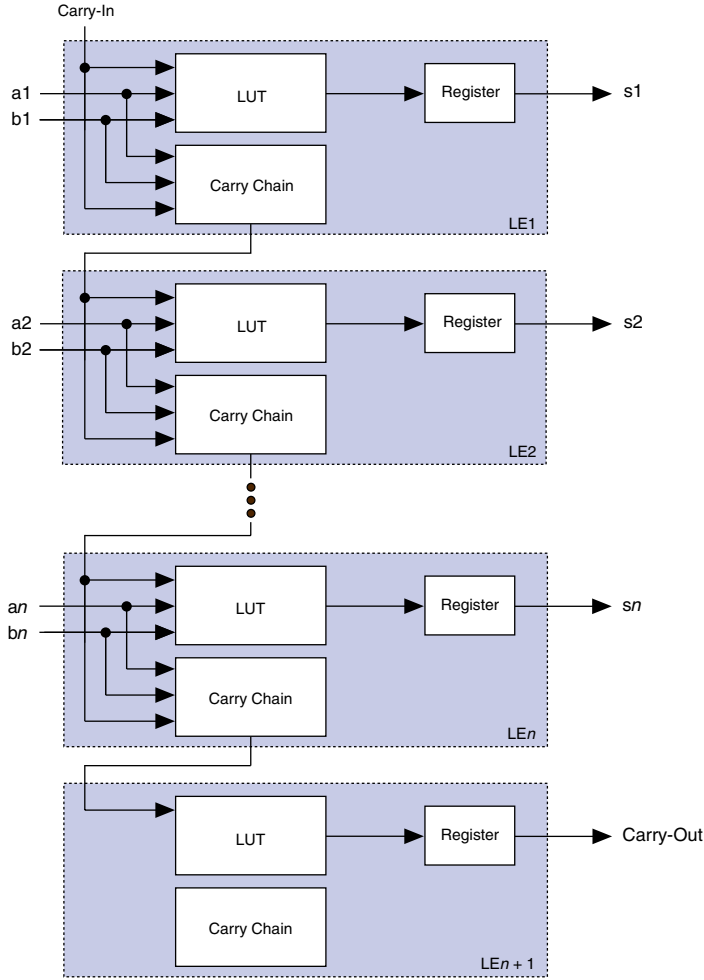
### *Carry Chain*

The carry chain provides a very fast carry-forward function between LEs. The carry-in signal from a lower-order bit drives forward into the higher-order bit via the carry chain, and feeds into both the LUT and the next portion of the carry chain. This feature allows the APEX 20K architecture to implement high-speed counters, adders, and comparators of arbitrary width. Carry chain logic can be created automatically by the Quartus II software Compiler during design processing, or manually by the designer during design entry. Parameterized functions such as library of parameterized modules (LPM) and DesignWare functions automatically take advantage of carry chains for the appropriate functions.

The Quartus II software Compiler creates carry chains longer than ten LEs by linking LABs together automatically. For enhanced fitting, a long carry chain skips alternate LABs in a MegaLAB™ structure. A carry chain longer than one LAB skips either from an even-numbered LAB to the next even-numbered LAB, or from an odd-numbered LAB to the next odd-numbered LAB. For example, the last LE of the first LAB in the upper-left MegaLAB structure carries to the first LE of the third LAB in the MegaLAB structure.

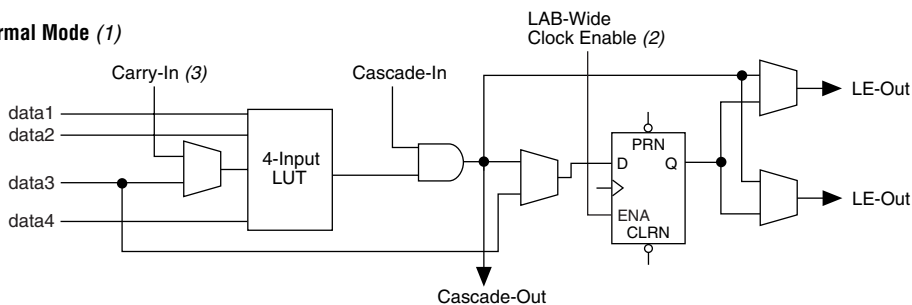
Figure 6 shows how an  $n$ -bit full adder can be implemented in  $n + 1$  LEs with the carry chain. One portion of the LUT generates the sum of two bits using the input signals and the carry-in signal; the sum is routed to the output of the LE. The register can be bypassed for simple adders or used for accumulator functions. Another portion of the LUT and the carry chain logic generates the carry-out signal, which is routed directly to the carry-in signal of the next-higher-order bit. The final carry-out signal is routed to an LE, where it is driven onto the local, MegaLAB, or FastTrack Interconnect routing structures.

Figure 6. APEX 20K Carry Chain

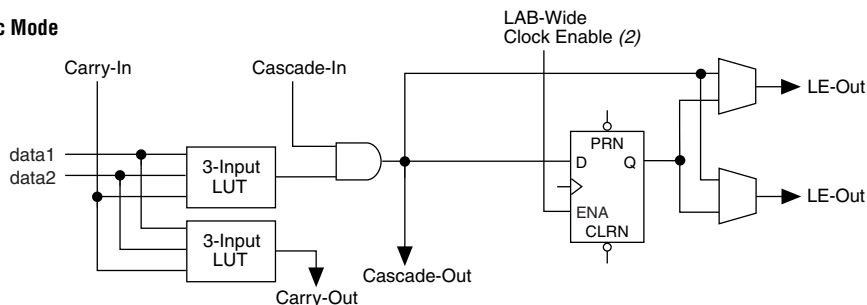


**Figure 8. APEX 20K LE Operating Modes**

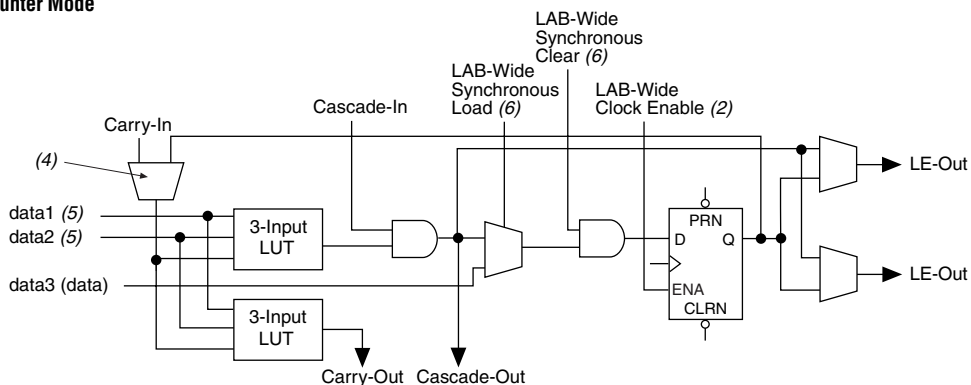
**Normal Mode (1)**



**Arithmetic Mode**



**Counter Mode**



**Notes to Figure 8:**

- (1) LEs in normal mode support register packing.
- (2) There are two LAB-wide clock enables per LAB.
- (3) When using the carry-in in normal mode, the packed register feature is unavailable.
- (4) A register feedback multiplexer is available on LE1 of each LAB.
- (5) The DATA1 and DATA2 input signals can supply counter enable, up or down control, or register feedback signals for LEs other than the second LE in an LAB.
- (6) The LAB-wide synchronous clear and LAB wide synchronous load affect all registers in an LAB.

The counter mode uses two three-input LUTs: one generates the counter data, and the other generates the fast carry bit. A 2-to-1 multiplexer provides synchronous loading, and another AND gate provides synchronous clearing. If the cascade function is used by an LE in counter mode, the synchronous clear or load overrides any signal carried on the cascade chain. The synchronous clear overrides the synchronous load. LEs in arithmetic mode can drive out registered and unregistered versions of the LUT output.

### *Clear & Preset Logic Control*

Logic for the register's clear and preset signals is controlled by LAB-wide signals. The LE directly supports an asynchronous clear function. The Quartus II software Compiler can use a NOT-gate push-back technique to emulate an asynchronous preset. Moreover, the Quartus II software Compiler can use a programmable NOT-gate push-back technique to emulate simultaneous preset and clear or asynchronous load. However, this technique uses three additional LEs per register. All emulation is performed automatically when the design is compiled. Registers that emulate simultaneous preset and load will enter an unknown state upon power-up or when the chip-wide reset is asserted.

In addition to the two clear and preset modes, APEX 20K devices provide a chip-wide reset pin (DEV\_CLRn) that resets all registers in the device. Use of this pin is controlled through an option in the Quartus II software that is set before compilation. The chip-wide reset overrides all other control signals. Registers using an asynchronous preset are preset when the chip-wide reset is asserted; this effect results from the inversion technique used to implement the asynchronous preset.

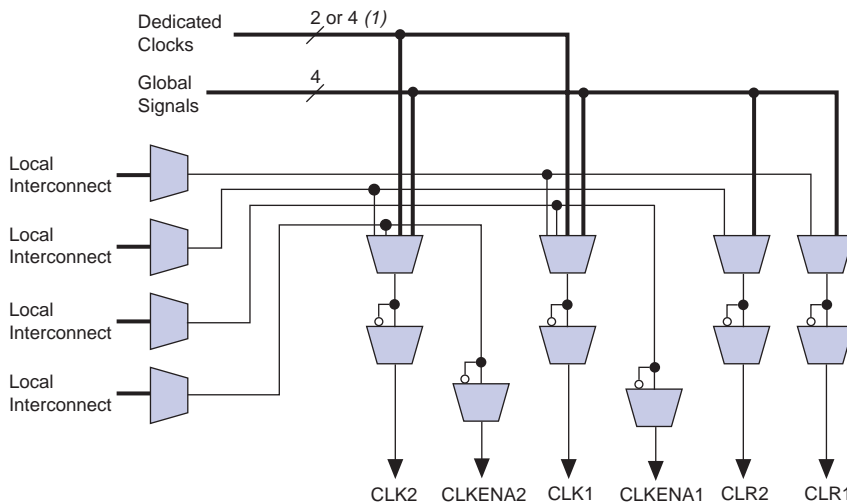
## **FastTrack Interconnect**

In the APEX 20K architecture, connections between LEs, ESBs, and I/O pins are provided by the FastTrack Interconnect. The FastTrack Interconnect is a series of continuous horizontal and vertical routing channels that traverse the device. This global routing structure provides predictable performance, even in complex designs. In contrast, the segmented routing in FPGAs requires switch matrices to connect a variable number of routing paths, increasing the delays between logic resources and reducing performance.

The FastTrack Interconnect consists of row and column interconnect channels that span the entire device. The row interconnect routes signals throughout a row of MegaLAB structures; the column interconnect routes signals throughout a column of MegaLAB structures. When using the row and column interconnect, an LE, IOE, or ESB can drive any other LE, IOE, or ESB in a device. See [Figure 9](#).

The programmable register also supports an asynchronous clear function. Within the ESB, two asynchronous clears are generated from global signals and the local interconnect. Each macrocell can either choose between the two asynchronous clear signals or choose to not be cleared. Either of the two clear signals can be inverted within the ESB. Figure 15 shows the ESB control logic when implementing product-terms.

**Figure 15. ESB Product-Term Mode Control Logic**



**Note to Figure 15:**

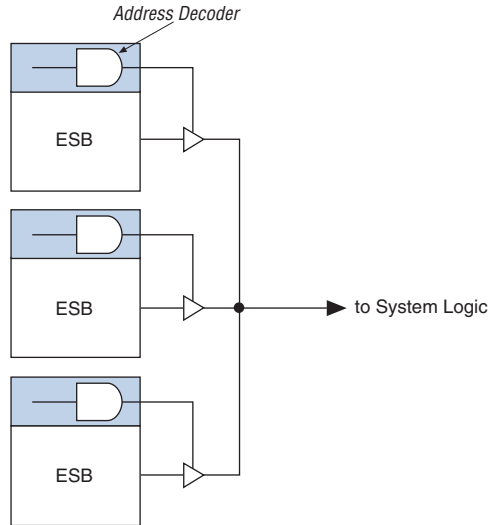
(1) APEX 20KE devices have four dedicated clocks.

### Parallel Expanders

Parallel expanders are unused product terms that can be allocated to a neighboring macrocell to implement fast, complex logic functions. Parallel expanders allow up to 32 product terms to feed the macrocell OR logic directly, with two product terms provided by the macrocell and 30 parallel expanders provided by the neighboring macrocells in the ESB.

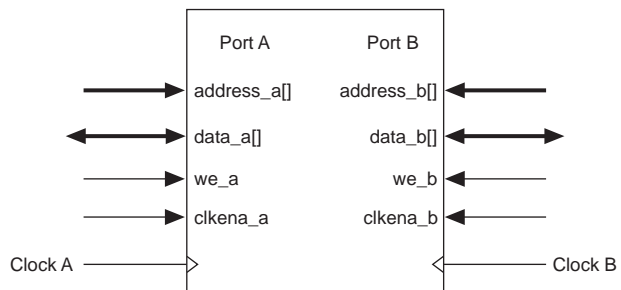
The Quartus II software Compiler can allocate up to 15 sets of up to two parallel expanders per set to the macrocells automatically. Each set of two parallel expanders incurs a small, incremental timing delay. Figure 16 shows the APEX 20K parallel expanders.

**Figure 18. Deep Memory Block Implemented with Multiple ESBs**



The ESB implements two forms of dual-port memory: read/write clock mode and input/output clock mode. The ESB can also be used for bidirectional, dual-port memory applications in which two ports read or write simultaneously. To implement this type of dual-port memory, two or four ESBs are used to support two simultaneous reads or writes. This functionality is shown in [Figure 19](#).

**Figure 19. APEX 20K ESB Implementing Dual-Port RAM**





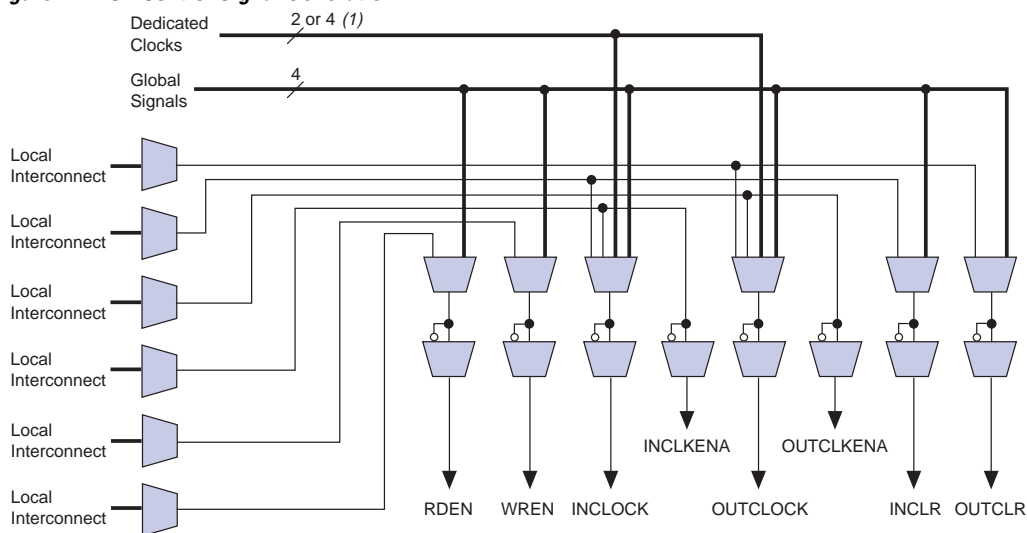


For more information on APEX 20KE devices and CAM, see *Application Note 119 (Implementing High-Speed Search Applications with APEX CAM)*.

## Driving Signals to the ESB

ESBs provide flexible options for driving control signals. Different clocks can be used for the ESB inputs and outputs. Registers can be inserted independently on the data input, data output, read address, write address, WE, and RE signals. The global signals and the local interconnect can drive the WE and RE signals. The global signals, dedicated clock pins, and local interconnect can drive the ESB clock signals. Because the LEs drive the local interconnect, the LEs can control the WE and RE signals and the ESB clock, clock enable, and asynchronous clear signals. [Figure 24](#) shows the ESB control signal generation logic.

**Figure 24. ESB Control Signal Generation**



**Note to Figure 24:**

(1) APEX 20KE devices have four dedicated clocks.

An ESB is fed by the local interconnect, which is driven by adjacent LEs (for high-speed connection to the ESB) or the MegaLAB interconnect. The ESB can drive the local, MegaLAB, or FastTrack Interconnect routing structure to drive LEs and IOEs in the same MegaLAB structure or anywhere in the device.

**Table 18. APEX 20KE Clock Input & Output Parameters (Part 1 of 2)** *Note (1)*

Symbol	Parameter	I/O Standard	-1X Speed Grade		-2X Speed Grade		Units
			Min	Max	Min	Max	
$f_{VCO}$ (4)	Voltage controlled oscillator operating range		200	500	200	500	MHz
$f_{CLOCK0}$	clock0 PLL output frequency for internal use		1.5	335	1.5	200	MHz
$f_{CLOCK1}$	clock1 PLL output frequency for internal use		20	335	20	200	MHz
$f_{CLOCK0\_EXT}$	Output clock frequency for external clock0 output	3.3-V LVTTTL	1.5	245	1.5	226	MHz
		2.5-V LVTTTL	1.5	234	1.5	221	MHz
		1.8-V LVTTTL	1.5	223	1.5	216	MHz
		GTL+	1.5	205	1.5	193	MHz
		SSTL-2 Class I	1.5	158	1.5	157	MHz
		SSTL-2 Class II	1.5	142	1.5	142	MHz
		SSTL-3 Class I	1.5	166	1.5	162	MHz
		SSTL-3 Class II	1.5	149	1.5	146	MHz
		LVDS	1.5	420	1.5	350	MHz
$f_{CLOCK1\_EXT}$	Output clock frequency for external clock1 output	3.3-V LVTTTL	20	245	20	226	MHz
		2.5-V LVTTTL	20	234	20	221	MHz
		1.8-V LVTTTL	20	223	20	216	MHz
		GTL+	20	205	20	193	MHz
		SSTL-2 Class I	20	158	20	157	MHz
		SSTL-2 Class II	20	142	20	142	MHz
		SSTL-3 Class I	20	166	20	162	MHz
		SSTL-3 Class II	20	149	20	146	MHz
		LVDS	20	420	20	350	MHz

## IEEE Std. 1149.1 (JTAG) Boundary-Scan Support

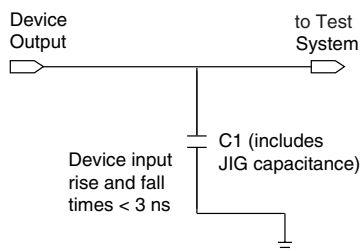
All APEX 20K devices provide JTAG BST circuitry that complies with the IEEE Std. 1149.1-1990 specification. JTAG boundary-scan testing can be performed before or after configuration, but not during configuration. APEX 20K devices can also use the JTAG port for configuration with the Quartus II software or with hardware using either Jam Files (.jam) or Jam Byte-Code Files (.jbc). Finally, APEX 20K devices use the JTAG port to monitor the logic operation of the device with the SignalTap embedded logic analyzer. APEX 20K devices support the JTAG instructions shown in Table 19. Although EP20K1500E devices support the JTAG BYPASS and SignalTap instructions, they do not support boundary-scan testing or the use of the JTAG port for configuration.

**Table 19. APEX 20K JTAG Instructions**

JTAG Instruction	Description
SAMPLE/PRELOAD	Allows a snapshot of signals at the device pins to be captured and examined during normal device operation, and permits an initial data pattern to be output at the device pins. Also used by the SignalTap embedded logic analyzer.
EXTEST	Allows the external circuitry and board-level interconnections to be tested by forcing a test pattern at the output pins and capturing test results at the input pins.
BYPASS (1)	Places the 1-bit bypass register between the TDI and TDO pins, which allows the BST data to pass synchronously through selected devices to adjacent devices during normal device operation.
USERCODE	Selects the 32-bit USERCODE register and places it between the TDI and TDO pins, allowing the USERCODE to be serially shifted out of TDO.
IDCODE	Selects the IDCODE register and places it between TDI and TDO, allowing the IDCODE to be serially shifted out of TDO.
ICR Instructions	Used when configuring an APEX 20K device via the JTAG port with a MasterBlaster™ or ByteBlasterMV™ download cable, or when using a Jam File or Jam Byte-Code File via an embedded processor.
SignalTap Instructions (1)	Monitors internal device operation with the SignalTap embedded logic analyzer.

**Note to Table 19:**

(1) The EP20K1500E device supports the JTAG BYPASS instruction and the SignalTap instructions.

**Figure 32. APEX 20K AC Test Conditions** *Note (1)*

**Note to Figure 32:**

- (1) Power supply transients can affect AC measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under AC conditions. Large-amplitude, fast-ground-current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, significant reductions in observable noise immunity can result.

## Operating Conditions

Tables 23 through 26 provide information on absolute maximum ratings, recommended operating conditions, DC operating conditions, and capacitance for 2.5-V APEX 20K devices.

**Table 23. APEX 20K 5.0-V Tolerant Device Absolute Maximum Ratings** *Notes (1), (2)*

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CCINT}$	Supply voltage	With respect to ground (3)	–0.5	3.6	V
$V_{CCIO}$			–0.5	4.6	V
$V_I$			–2.0	5.75	V
$I_{OUT}$	DC output current, per pin		–25	25	mA
$T_{STG}$	Storage temperature	No bias	–65	150	°C
$T_{AMB}$	Ambient temperature	Under bias	–65	135	°C
$T_J$	Junction temperature	PQFP, RQFP, TQFP, and BGA packages, under bias		135	°C
		Ceramic PGA packages, under bias		150	°C

**Table 25. APEX 20K 5.0-V Tolerant Device DC Operating Conditions (Part 2 of 2)** *Notes (2), (7), (8)*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{OL}$	3.3-V low-level TTL output voltage	$I_{OL} = 12 \text{ mA DC}$ , $V_{CCIO} = 3.00 \text{ V}$ (11)			0.45	V
	3.3-V low-level CMOS output voltage	$I_{OL} = 0.1 \text{ mA DC}$ , $V_{CCIO} = 3.00 \text{ V}$ (11)			0.2	V
	3.3-V low-level PCI output voltage	$I_{OL} = 1.5 \text{ mA DC}$ , $V_{CCIO} = 3.00 \text{ to } 3.60 \text{ V}$ (11)			$0.1 \times V_{CCIO}$	V
	2.5-V low-level output voltage	$I_{OL} = 0.1 \text{ mA DC}$ , $V_{CCIO} = 2.30 \text{ V}$ (11)			0.2	V
		$I_{OL} = 1 \text{ mA DC}$ , $V_{CCIO} = 2.30 \text{ V}$ (11)			0.4	V
		$I_{OL} = 2 \text{ mA DC}$ , $V_{CCIO} = 2.30 \text{ V}$ (11)			0.7	V
$I_I$	Input pin leakage current	$V_I = 5.75 \text{ to } -0.5 \text{ V}$	-10		10	$\mu\text{A}$
$I_{OZ}$	Tri-stated I/O pin leakage current	$V_O = 5.75 \text{ to } -0.5 \text{ V}$	-10		10	$\mu\text{A}$
$I_{CC0}$	$V_{CC}$ supply current (standby) (All ESBs in power-down mode)	$V_I = \text{ground}$ , no load, no toggling inputs, -1 speed grade (12)		10		mA
		$V_I = \text{ground}$ , no load, no toggling inputs, -2, -3 speed grades (12)		5		mA
$R_{CONF}$	Value of I/O pin pull-up resistor before and during configuration	$V_{CCIO} = 3.0 \text{ V}$ (13)	20		50	W
		$V_{CCIO} = 2.375 \text{ V}$ (13)	30		80	W

**Table 31. APEX 20K  $t_{MAX}$  Timing Parameters (Part 2 of 2)**

Symbol	Parameter
$t_{ESB\text{DATA}CO2}$	ESB clock-to-output delay without output registers
$t_{ESBDD}$	ESB data-in to data-out delay for RAM mode
$t_{PD}$	ESB macrocell input to non-registered output
$t_{PTERMSU}$	ESB macrocell register setup time before clock
$t_{PTERMCO}$	ESB macrocell register clock-to-output delay
$t_{F1-4}$	Fanout delay using local interconnect
$t_{F5-20}$	Fanout delay using MegaLab Interconnect
$t_{F20+}$	Fanout delay using FastTrack Interconnect
$t_{CH}$	Minimum clock high time from clock pin
$t_{CL}$	Minimum clock low time from clock pin
$t_{CLRP}$	LE clear pulse width
$t_{PREP}$	LE preset pulse width
$t_{ESBCH}$	Clock high time
$t_{ESBCL}$	Clock low time
$t_{ESBWP}$	Write pulse width
$t_{ESBRP}$	Read pulse width

Tables 32 and 33 describe APEX 20K external timing parameters.

**Table 32. APEX 20K External Timing Parameters Note (1)**

Symbol	Clock Parameter
$t_{INSU}$	Setup time with global clock at IOE register
$t_{INH}$	Hold time with global clock at IOE register
$t_{OUTCO}$	Clock-to-output delay with global clock at IOE register

**Table 33. APEX 20K External Bidirectional Timing Parameters Note (1)**

Symbol	Parameter	Conditions
$t_{INSUBIDIR}$	Setup time for bidirectional pins with global clock at same-row or same-column LE register	
$t_{INH\text{BIDIR}}$	Hold time for bidirectional pins with global clock at same-row or same-column LE register	
$t_{OUTCO\text{BIDIR}}$	Clock-to-output delay for bidirectional pins with global clock at IOE register	C1 = 10 pF
$t_{XZ\text{BIDIR}}$	Synchronous IOE output buffer disable delay	C1 = 10 pF
$t_{ZXBIDIR}$	Synchronous IOE output buffer enable delay, slow slew rate = off	C1 = 10 pF

**Table 42. EP20K400  $f_{MAX}$  Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Units
	Min	Max	Min	Max	Min	Max	
$t_{SU}$	0.1		0.3		0.6		ns
$t_H$	0.5		0.8		0.9		ns
$t_{CO}$		0.1		0.4		0.6	ns
$t_{LUT}$		1.0		1.2		1.4	ns
$t_{ESBRC}$		1.7		2.1		2.4	ns
$t_{ESBWC}$		5.7		6.9		8.1	ns
$t_{ESBWESU}$	3.3		3.9		4.6		ns
$t_{ESBDATASU}$	2.2		2.7		3.1		ns
$t_{ESBDATAH}$	0.6		0.8		0.9		ns
$t_{ESBADDRSU}$	2.4		2.9		3.3		ns
$t_{ESBDATACO1}$		1.3		1.6		1.8	ns
$t_{ESBDATACO2}$		2.5		3.1		3.6	ns
$t_{ESBDD}$		2.5		3.3		3.6	ns
$t_{PD}$		2.5		3.1		3.6	ns
$t_{PTERMSU}$	1.7		2.1		2.4		ns
$t_{PTERMCO}$		1.0		1.2		1.4	ns
$t_{F1-4}$		0.4		0.5		0.6	ns
$t_{F5-20}$		2.6		2.8		2.9	ns
$t_{F20+}$		3.7		3.8		3.9	ns
$t_{CH}$	2.0		2.5		3.0		ns
$t_{CL}$	2.0		2.5		3.0		ns
$t_{CLRP}$	0.5		0.6		0.8		ns
$t_{PREP}$	0.5		0.5		0.5		ns
$t_{ESBCH}$	2.0		2.5		3.0		ns
$t_{ESBCL}$	2.0		2.5		3.0		ns
$t_{ESBWP}$	1.5		1.9		2.2		ns
$t_{ESBRP}$	1.0		1.2		1.4		ns

Tables 43 through 48 show the I/O external and external bidirectional timing parameter values for EP20K100, EP20K200, and EP20K400 APEX 20K devices.

**Table 43. EP20K100 External Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSU</sub> (1)	2.3		2.8		3.2		ns
t <sub>INH</sub> (1)	0.0		0.0		0.0		ns
t <sub>OUTCO</sub> (1)	2.0	4.5	2.0	4.9	2.0	6.6	ns
t <sub>INSU</sub> (2)	1.1		1.2		—		ns
t <sub>INH</sub> (2)	0.0		0.0		—		ns
t <sub>OUTCO</sub> (2)	0.5	2.7	0.5	3.1	—	4.8	ns

**Table 44. EP20K100 External Bidirectional Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSUBIDIR</sub> (1)	2.3		2.8		3.2		ns
t <sub>INHBIDIR</sub> (1)	0.0		0.0		0.0		ns
t <sub>OUTCOBIDIR</sub> (1)	2.0	4.5	2.0	4.9	2.0	6.6	ns
t <sub>XZBIDIR</sub> (1)		5.0		5.9		6.9	ns
t <sub>ZXBIDIR</sub> (1)		5.0		5.9		6.9	ns
t <sub>INSUBIDIR</sub> (2)	1.0		1.2		—		ns
t <sub>INHBIDIR</sub> (2)	0.0		0.0		—		ns
t <sub>OUTCOBIDIR</sub> (2)	0.5	2.7	0.5	3.1	—	—	ns
t <sub>XZBIDIR</sub> (2)		4.3		5.0		—	ns
t <sub>ZXBIDIR</sub> (2)		4.3		5.0		—	ns

**Table 45. EP20K200 External Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSU</sub> (1)	1.9		2.3		2.6		ns
t <sub>INH</sub> (1)	0.0		0.0		0.0		ns
t <sub>OUTCO</sub> (1)	2.0	4.6	2.0	5.6	2.0	6.8	ns
t <sub>INSU</sub> (2)	1.1		1.2		—		ns
t <sub>INH</sub> (2)	0.0		0.0		—		ns
t <sub>OUTCO</sub> (2)	0.5	2.7	0.5	3.1	—	—	ns



**Table 87. EP20K400E  $t_{MAX}$  Routing Delays**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{F1-4}$		0.25		0.25		0.26	ns
$t_{F5-20}$		1.01		1.12		1.25	ns
$t_{F20+}$		3.71		3.92		4.17	ns

**Table 88. EP20K400E Minimum Pulse Width Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{CH}$	1.36		2.22		2.35		ns
$t_{CL}$	1.36		2.26		2.35		ns
$t_{CLRP}$	0.18		0.18		0.19		ns
$t_{PREP}$	0.18		0.18		0.19		ns
$t_{ESBCH}$	1.36		2.26		2.35		ns
$t_{ESBCL}$	1.36		2.26		2.35		ns
$t_{ESBWP}$	1.17		1.38		1.56		ns
$t_{ESBRP}$	0.94		1.09		1.25		ns

**Table 89. EP20K400E External Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{INSU}$	2.51		2.64		2.77		ns
$t_{INH}$	0.00		0.00		0.00		ns
$t_{OUTCO}$	2.00	5.25	2.00	5.79	2.00	6.32	ns
$t_{INSUPLL}$	3.221		3.38		-		ns
$t_{INHPLL}$	0.00		0.00		-		ns
$t_{OUTCOPLL}$	0.50	2.25	0.50	2.45	-	-	ns

**Table 92. EP20K600E  $t_{MAX}$  ESB Timing Microparameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{ESBARC}$		1.67		2.39		3.11	ns
$t_{ESBSRC}$		2.27		3.07		3.86	ns
$t_{ESBAWC}$		3.19		4.56		5.93	ns
$t_{ESBSWC}$		3.51		4.62		5.72	ns
$t_{ESBWASU}$	1.46		2.08		2.70		ns
$t_{ESBWAH}$	0.00		0.00		0.00		ns
$t_{ESBWDSU}$	1.60		2.29		2.97		ns
$t_{ESBWDH}$	0.00		0.00		0.00		ns
$t_{ESBRASU}$	1.61		2.30		2.99		ns
$t_{ESBRAH}$	0.00		0.00		0.00		ns
$t_{ESBWESU}$	1.49		2.30		3.11		ns
$t_{ESBWEH}$	0.00		0.00		0.00		ns
$t_{ESBDATASU}$	-0.01		0.35		0.71		ns
$t_{ESBDATAH}$	0.13		0.13		0.13		ns
$t_{ESBWADDRSU}$	0.19		0.62		1.06		ns
$t_{ESBRADDRSU}$	0.25		0.71		1.17		ns
$t_{ESBDATAO1}$		1.01		1.19		1.37	ns
$t_{ESBDATAO2}$		2.18		3.12		4.05	ns
$t_{ESBDD}$		3.19		4.56		5.93	ns
$t_{PD}$		1.57		2.25		2.92	ns
$t_{PTERMSU}$	0.85		1.43		2.01		ns
$t_{PTERMCO}$		1.03		1.21		1.39	ns

**Table 93. EP20K600E  $t_{MAX}$  Routing Delays**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{F1-4}$		0.22		0.25		0.26	ns
$t_{F5-20}$		1.26		1.39		1.52	ns
$t_{F20+}$		3.51		3.88		4.26	ns

**Table 94. EP20K600E Minimum Pulse Width Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>CH</sub>	2.00		2.50		2.75		ns
t <sub>CL</sub>	2.00		2.50		2.75		ns
t <sub>CLRP</sub>	0.18		0.26		0.34		ns
t <sub>PREP</sub>	0.18		0.26		0.34		ns
t <sub>ESBCH</sub>	2.00		2.50		2.75		ns
t <sub>ESBCL</sub>	2.00		2.50		2.75		ns
t <sub>ESBWP</sub>	1.17		1.68		2.18		ns
t <sub>ESBRP</sub>	0.95		1.35		1.76		ns

**Table 95. EP20K600E External Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSU</sub>	2.74		2.74		2.87		ns
t <sub>INH</sub>	0.00		0.00		0.00		ns
t <sub>OUTCO</sub>	2.00	5.51	2.00	6.06	2.00	6.61	ns
t <sub>INSUPLL</sub>	1.86		1.96		-		ns
t <sub>INHPLL</sub>	0.00		0.00		-		ns
t <sub>OUTCOPLL</sub>	0.50	2.62	0.50	2.91	-	-	ns

**Table 96. EP20K600E External Bidirectional Timing Parameters**

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSUBIDIR</sub>	0.64		0.98		1.08		ns
t <sub>INHBIDIR</sub>	0.00		0.00		0.00		ns
t <sub>OUTCOBIDIR</sub>	2.00	5.51	2.00	6.06	2.00	6.61	ns
t <sub>XZBIDIR</sub>		6.10		6.74		7.10	ns
t <sub>ZXBIDIR</sub>		6.10		6.74		7.10	ns
t <sub>INSUBIDIRPLL</sub>	2.26		2.68		-		ns
t <sub>INHBIDIRPLL</sub>	0.00		0.00		-		ns
t <sub>OUTCOBIDIRPLL</sub>	0.50	2.62	0.50	2.91	-	-	ns
t <sub>XZBIDIRPLL</sub>		3.21		3.59		-	ns
t <sub>ZXBIDIRPLL</sub>		3.21		3.59		-	ns

## Revision History

The information contained in the *APEX 20K Programmable Logic Device Family Data Sheet* version 5.1 supersedes information published in previous versions.

### Version 5.1

*APEX 20K Programmable Logic Device Family Data Sheet* version 5.1 contains the following changes:

- In version 5.0, the VI input voltage spec was updated in Table 28 on page 63.
- In version 5.0, *Note (5)* to Tables 27 through 30 was revised.
- Added *Note (2)* to Figure 21 on page 33.

### Version 5.0

*APEX 20K Programmable Logic Device Family Data Sheet* version 5.0 contains the following changes:

- Updated Tables 23 through 26. Removed 2.5-V operating condition tables because all APEX 20K devices are now 5.0-V tolerant.
- Updated conditions in Tables 33, 38 and 39.
- Updated data for  $t_{\text{ESB DATAH}}$  parameter.

### Version 4.3

*APEX 20K Programmable Logic Device Family Data Sheet* version 4.3 contains the following changes:

- Updated Figure 20.
- Updated *Note (2)* to Table 13.
- Updated notes to Tables 27 through 30.

### Version 4.2

*APEX 20K Programmable Logic Device Family Data Sheet* version 4.2 contains the following changes:

- Updated Figure 29.
- Updated *Note (1)* to Figure 29.



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